

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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|---------------------------------------|---|---------------------------|
| In re Application |) | <u>PATENT APPLICATION</u> |
| |) | |
| Inventor: Jian Chen, et al. |) | |
| |) | Art Unit: 2824 |
| Application No.: 10/765,963 |) | |
| |) | Examiner: Tran, Andrew Q. |
| Filed Date: January 26, 2004 |) | |
| |) | Customer No.: 64948 |
| Title: METHOD OF READING NAND MEMORY) |) | |
| TO COMPENSATE FOR COUPLING BETWEEN) |) | |
| STORAGE ELEMENTS |) | |

RESPONSE B TO OFFICE ACTION UNDER 37 C.F.R. § 1.116

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

*Entry denied -
at
09/17/2007*

This RESPONSE B is in reply to the Office Action mailed June 11, 2007.

AMENDMENTS TO THE CLAIMS are reflected in the listing of claims which begin on page 2 of this Response.

AMENDMENTS TO THE ABSTRACT are reflected in the listing of claims which begin on page 6 of this Response.

REMARKS begin on Page 7 of this Response.